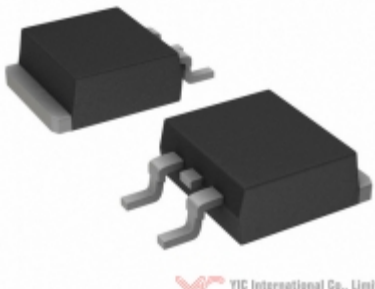

	<h2 style="color: #E67E22;">FQB25N33TM</h2>
 <p style="font-size: small;">Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB25N33TM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 330V 25A D2PAK
	Datenblätter:  FQB25N33TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 21999 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB25N33TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 330V 25A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	21999 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.1W (Ta), 250W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	330V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	25A (Tc)
Rds On (Max) @ Id, Vgs	230 mOhm @ 12.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	75nC @ 15V
Eingabekapazität (Ciss) (Max) @ Vds	2010pF @ 25V
Verpackung	Tape & Reel (TR)


FQB25N33TM ist neu im Original, Suche FQB25N33TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB25N33TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB25N33TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB25N33TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB27N25TM FAIRCH FQB27N25TM FAIRCH</p>	 <p>FQB25N33 FAIRCHI FQB25N33 FAIRCHI</p>	 <p>FQB25N33TM_F085 Fairchild/ON Semiconductor FQB25N33TM_F085 Fairchild/ON Semiconductor</p>
 <p>FQB24N08TM Fairchild/ON Semiconductor MOSFET N-CH 80V 24A D2PAK</p>	 <p>FQB25N33TM-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB24N08 FSC FSC TO-263</p>	 <p>FQB27N25TM-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A 131M</p>

heiße Teile

Mehr

 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C
 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM	 FQB19N20LTM
 FQB19N20TM	 FQB19N20TM	 FQB1N60TM	 FQB1N60TM	 FQB20N06L
 FQB20N60FTM	 FQB20N60TM	 FQB22P10	 FQB22P10TM	 FQB22P10TM
 FQB22P10TM_F085	 FQB24N08TM	 FQB24N08TM	 FQB25N33	 FQB25N33TM
 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM
 FQB2N50C	 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM
 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06
 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM
 FQB32N12V2	 FQB32N12V2TM	 FQB32N12V2TM	 FQB32N20	 FQB32N20C

Contact us: Info@Y-IC.com

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